

# 30V/8A High-Speed Switching Applications

## **Applications**

· Large current switching of relay drivers, high-speed inverters, converters.

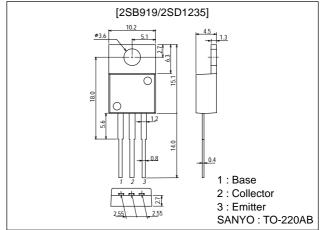
#### **Features**

- · Low collector-to-emitter saturation voltage : V<sub>CE(sat)</sub>=-0.5V (PNP), 0.4V (NPN) max.
- · Large current capacity.

# unit:mm

**Package Dimensions** 

2010C



(): 2SB919

## **Specifications**

#### **Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(-)60	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		(-)30	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		(-)6	V
Collector Current	ΙC		(–)8	Α
Collector Current (Pulse)	I <sub>CP</sub>		(–)15	Α
Collector Dissipation	D <sub>0</sub>		1.75	W
Collector Dissipation	PC	Tc=25°C	30	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### **Electrical Characteristics** at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	I <sub>CBO</sub>	V <sub>CB</sub> =(-)40V, I <sub>E</sub> =0			(–)0.1	mA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)4V, I <sub>C</sub> =0			(-)0.1	mA
C Current Gain	h <sub>FE</sub> 1	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)1A	70*		280*	
DC Current Gain	h <sub>FE</sub> 2	V <sub>CE</sub> =(-)2V, I <sub>C</sub> =(-)4A	30			
Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)1A		120		MHz

<sup>\*:</sup> The 2SB919/2SD1235 are classified as follows according to hFE at 1A.

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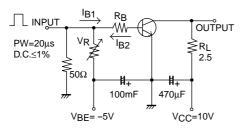
Rank	Q	R	S		
hFE	70 to 140	100 to 200	140 to 280		

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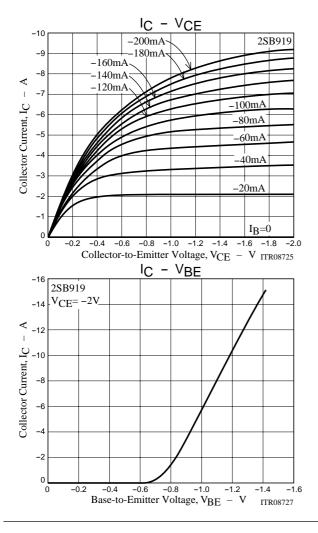
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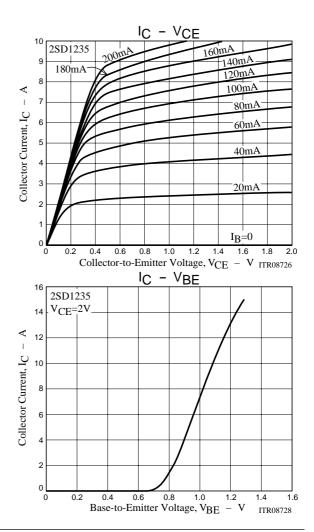
Parameter	Symbol	Conditions	Ratings			Unit
Farameter	Symbol		min	typ	max	O I III
Collector-to-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =(-)3A, I <sub>B</sub> =(-)0.15A			0.4	V
					(-0.5)	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =(-)1mA, I <sub>E</sub> =0	(-)60			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =(−)1mA, R <sub>BE</sub> =∞	(-)30			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I <sub>E</sub> =(-)1mA I <sub>C</sub> =0	(-)6			V
Turn-ON Time	ton	See specified Test Circuit		0.1		μs
Storage Time	t <sub>stg</sub>	See specified Test Circuit		(0.2)		μs
				0.5		μs
Fall Time	t <sub>f</sub>	See specified Test Circuit		0.03		μs

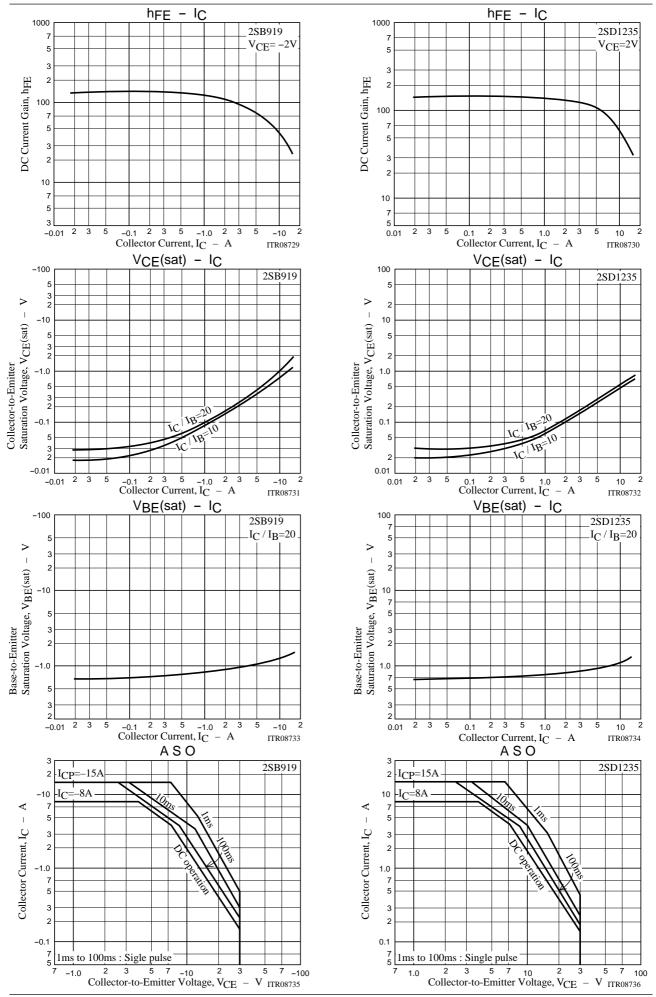
#### **Switching Time Test Circuit**

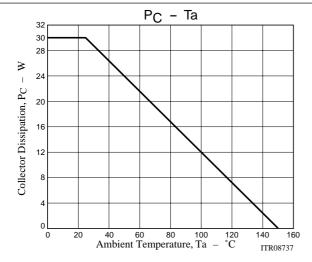


20I<sub>B1</sub>= -20I<sub>B2</sub>=I<sub>C</sub>=4A (For PNP, the polarity is reversed.)









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